

No.4298A

LA1831, 1831M

Support for AM Stereo and Electronic Tuning Single Chip Music Center IC (AM/FM IF + MPX) for Use in Compact Radio/Casette Products

Overview

The LA1831 is a single chip AM/FM IF and MPX tuner IC that supports electronic tuning. This chip was developed for consumer audio systems and is optimal for auto-seek systems based on IF count methods used together with SD.

Since no adjustments are required in the FM detector and MPX VCO circuits, use of this chip can significantly reduce the number of adjustment steps in the end-product manufacturing line.

Functions

AM: RF amplifier, mixer, oscillator (with ALC), IF amplifier, detector AGC, oscillator buffer,

tuning indicator, IF buffer output, stereo IF output.

FM IF: IF amplifier, quadrature detector, S curve detection, tuning indicator, IF buffer output,

S-meter

MPX: PLL stereo decoder, stereo indicator, force to

mono, VCO stop

Features

- · Major reduction in required adjustments
 - FM detector: No adjustments

(ceramic discriminator used)

- MPX VCO: No adjustments

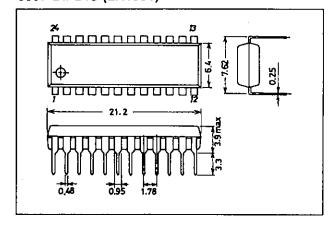
(ceramic resonator used)

- Tuning indicator pin provided (can be used as a narrow bandwidth stop signal or a muting drive output): SD output
- Supports IF count methods
- · Variable FM stop sensitivity and bandwidth
- Built-in AM local oscillator buffer
- Supports AM low-cut control
- Pin compatible with the LA1830 (only the DIP version, the LA1831M is a new product)
- · Built-in IF output function for AM stereo

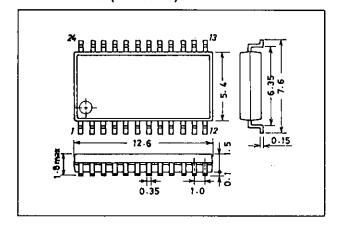
Package Dimensions

unit: mm

3067-DIP24S (LA1831)



3112-MFP24S (LA1831M)



Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Condition	Rating	Unit
Maximum supply voltage	V _{cc} max		9.0	V
Indicator drive current	I _{LEO}	Pins 6 and 7	20	mΑ
Allowable power dissipation	Pd max	Ta ≤ 70°C (LA1831)	400	mW
		Ta = 70°C (LA1831M)	270	mW
Operating temperature	TopF		-20 to + 70	•℃
Storage temperature	T _{eig}		-40 to +125	•€

Operating conditions at Ta = 25°C

Parameter	Symbol	Rating	Unit
Recommended supply voltage	Vcc	5.0	٧
Operating supply voltage range	V _{cc} op	4.0 to 8.0	V

Operating Characteristics, at Ta = 25°C, $V_{CC} = 5.0$ V, (for the specified test circuits)

FM Characteristics (mono): fc = 10.7 MHz, fm = 1 kHz

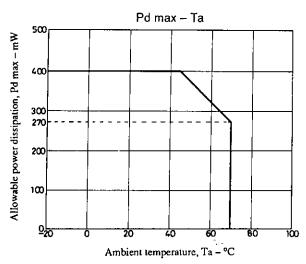
				Ratings		
Parameter	Symbol	Condition	min	typ	max	Unit
Quiescent current	I _{cco} -FM	No input 19	12	23	33	mA
Demodulation output	V _o -FM	100 dBµ, 100% mod, pin 14 output	290	410	580	mVrms
Channel balance	C.B	100 dBμ, 100% mod, ratio of pin 14 to pin 15	-1.5	0	1.5	dB
Total harmonic distortion (mono)	THD-FMmono	100 dBµ, 100% mod, pin 14 output	<u> </u>	0.3	1.5	%
Signal to noise ratio	S/N-FM	100 dBµ, 100% mod, pin 14 output	68	75		dB
Input limiting voltage	-3 dB L.S	With an input reference of 100 dBµ, the IF input that reduces the output by 3 dB		32	40	dВμ
LED sensitivity	V _{LED-SENS}	The IF input that turns the TU LED on	35	45	55	dΒμ
LED bandwidth	LED-BAND	The frequency bandwidth that turns the TU LED on 70 110		160	kHz	
IF count buffer output	V _{IFBUFF-FM}	The pin 10 output for 100 dBμ, no modulation 75 110		150	mVrms	

FM Characteristics (stereo): fc = 10.7 MHz, fm = 1 kHz, L + R = 90%, PILOT = 10%, V_{IN} = 100 dB μ

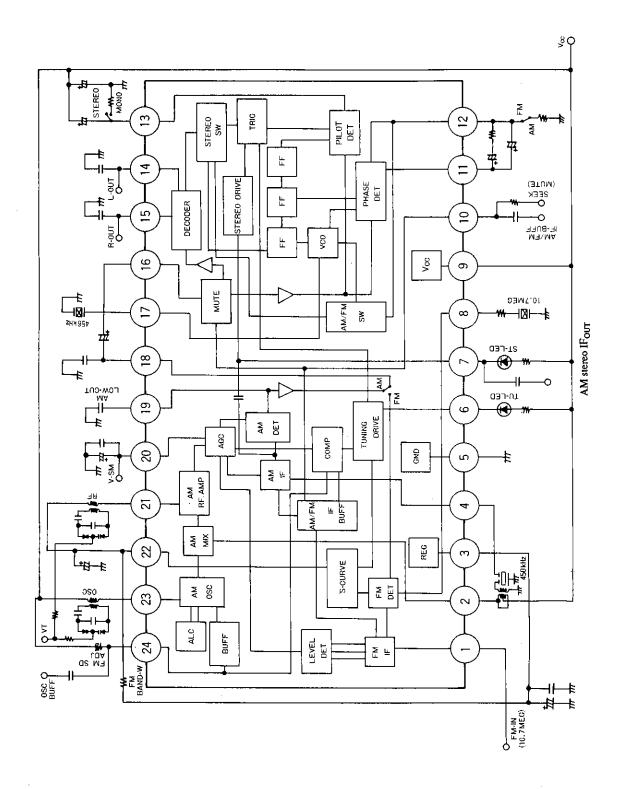
				Ratings		
Parameter	Symbol	Condition	min	typ	max	Unit
Separation	Sep	Pin 14 output	30	45		dB
Stereo on level	ST-ON	The pilot modulation level for which V_7 becomes less that 1.5 V	1,5	3.0	5.0	%
Total harmonic distortion (main)	THD-Main	Pin 14 output		0.3	1.5	%

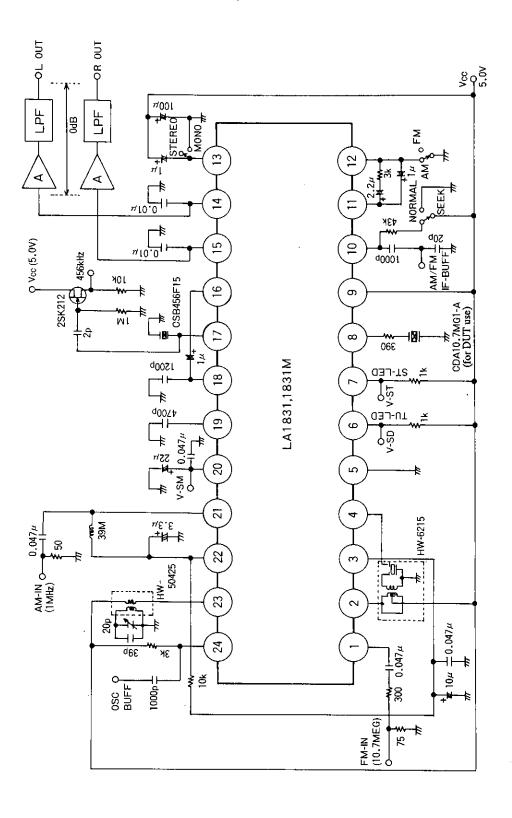
AM Characteristics: fc = 1000 kHz, fm = 1 kHz, 30% modulation

				 Ratings 		
Parameter	Symbol	Condition	min	typ	max	Unit
Quiescent current	I _{cco} -AM	No input 19	10	20	33	mA
Detector output	V _o 1	23 dBμ, pin 14 output	25	50	100	mVrms
	V _o 2	80 dBμ, pin 14 output	80	130	200	mVrms
Signal to noise ratio	S/N 1	23 dBμ, pin 14 output	16	20		ďΒ
	S/N 2	80 dBμ, pin 14 output	48	54	1	₫B
Total harmonic distortion	THD-AM	80 dBμ, pin 14 output		0.3	1.0	%
		100 dBµ, pin 14 output		0.4	1.2	%
LED sensitivity	V _{LEO-SENS}	The ANT input level at which the TU LED turns on		29	39	σВμ
Local oscillator buffer output	V _{OSC-AM}	No input, pin 24 output		200		mVrms
Low band attenuation	LOW-cut	Output when fm = 100 Hz, for a fm = 1 kHz reference		9	13	dB
IF count buffer output	V _{IFBUFF-AM}	80 dBμ, no modulation, pin 10 output 125 180 2		250	mVrms	
Stereo IF output	V _{ST} I _F -AM	80 dBμ, no modulation, pin 7 output 7.0 15.0			mVrms	



Equivalent Circuit Diagram





Unit (resistance: Ω, capacitance: F)

Pin Functions and No-Signal Voltages

No.	Function	Pin voltage (V)	Equivalent circuit	Notes
1	FM (F input	2.1	3	Input impedance $ri=330~\Omega$
2	AM MIX output	5.0	2	Used for the MIX coil between pin 2 and pin 9 (the V _{CC} voltage)
3	REG	2.1	3	V _{reg} = 2.1 V
4	AM IF input	2.1	4	Input impedance $r_i = 2 \text{ k}\Omega$
5	GND	0		
7	Tu-LED IF output for ST-LED and AM stereo	5.0	6 7	Active-(L) Open collector
8	FM-DET	2.8 (FM) 3.4 (AM)	8	Recommended ceramic discriminator: CDA10.7MG43 (Murata, Ltd)
9	V _{CC}	5.0		IC accept and mosts are transfer to the
10	AM/FM IF count output control SW, and mute SW	0	10	IF count and mute are turned on when V _{IO} > 3.0 V Note: During seek, the IF buffer is output only in the SD on state.
11	Phase comparator filter pin, and AM/FM switch	Pin 11 3.8 (FM) 1.5 (AM)	0-1-2-1-12	AM mode is selected when over 200 μA flows from pin 12
12		Pin 12 3.8 (FM) 0 (AM)		

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No.	Function	Pin voltage (V)	Equivalent circuit	Notes
13	Pilot detector filter pin, force to mono, VCO stop	3.5	13	Mode forced to mono when over 50 μA flows from this pin The VCO stops at currents over 200 μA
14	Left output	1.2	 	Output impedance $r_0 = 5 \text{ k}\Omega$
15	Right output		14 (15)	
16	MPX input	2.1	16	Input impedance $r_i = 20 \text{ k}\Omega$
17	MPX VCO	2.4 (FM) 0 (AM)	(17) 	Recommended ceramic oscillator: CSB456F15 (Murata, Ltd)
18	AM/FM demodulator output	2.1 (FM) 1.3 (AM)	18	Output impedance FM: $r_{\rm o}$ = 2.3 k Ω AM: $r_{\rm o}$ = 10 k Ω
19	AM LOW CUT	1.5 (FM) 2.0 (AM)	100k	The low band frequency characteristics are changed by an external capacitor connected at pin 19
20	S-meter, AM AGC	0.2 (FM) 0.6 (AM)	20 R	Built-in load resistance: $R=13.9~\mathrm{k}\Omega$ An external capacitor connected at pin 20 determines the seek time SD response speed
21	AM RF-IN	2.1	(21)	Pin 21 is used at the same potential as pin 22 (the AFC voltage)
22	AFC	2.1	22)	The FM-SD bandwidth can be changed with an external resistor connected between pin 22 and pin 3 Note: A setting of 180 kHz or higher is recommended for the FM-SD bandwidth.

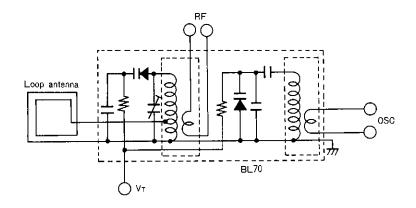
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No.	Function	Pin voltage (V)	Equivalent circuit	Notes
23	osc	5.0	23)	An oscillator coil is used between pin 23 and pin 9 (the V _{CC} voltage)
				Note: An oscillator coil with an impedance of 5 k $\!\Omega$ or over (secondary side) should be used.
24	OSC buffer, FM SD adj.	3.6	٦	The FM SD sensitivity can be changed with an external resistor connected at pin 24
			β 200 Ω 24	Note: A resistor of 3 k Ω or over should be used for the pin 24 external resistor.

Coll Specifications

AM ANT BLOCK



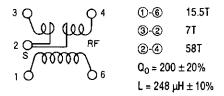
Loop antenna

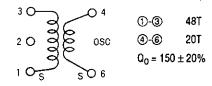
• LA300 (Kohringiken, Ltd.)

Loop antenna matching coil

• KL-412 (Kohringiken, Ltd.) (for use with the SVC321)

• KO-387 (Kohringiken, Ltd.) (for SVC321 use)





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AM OSC (for DUT use)
 HW-50425 (Mitsumi, Ltd.)

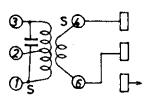
• IFT YD-1073-1 (Mitsumi, Ltd.)



- ③-② 2T ④-⑥ 9T ②-① 86T $Q_0 \ge 80$ L = 270 µH

(1)-(2) 58T (4)-(6) 7T (2)-(3) 94T (1) 450 kHz (2) 450 kHz (3) 9F internal (4) 450B

• IFT (for DUT use) HW-6215 (Mitsumi, Ltd.)

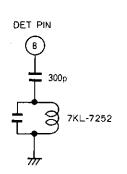


HW-6194 SFU-450B

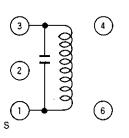
①-② 94T

(4)-(6)(2)-(3)(3)(5)(8)(7)(7)(8)(9

180 p



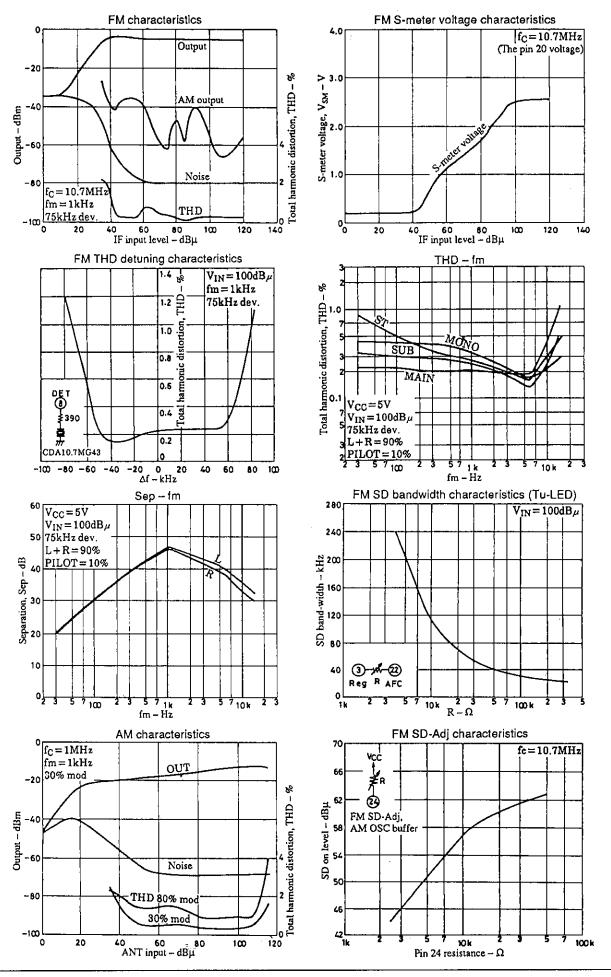
• FM DET 7KL-7252 (Toko, Ltd.)

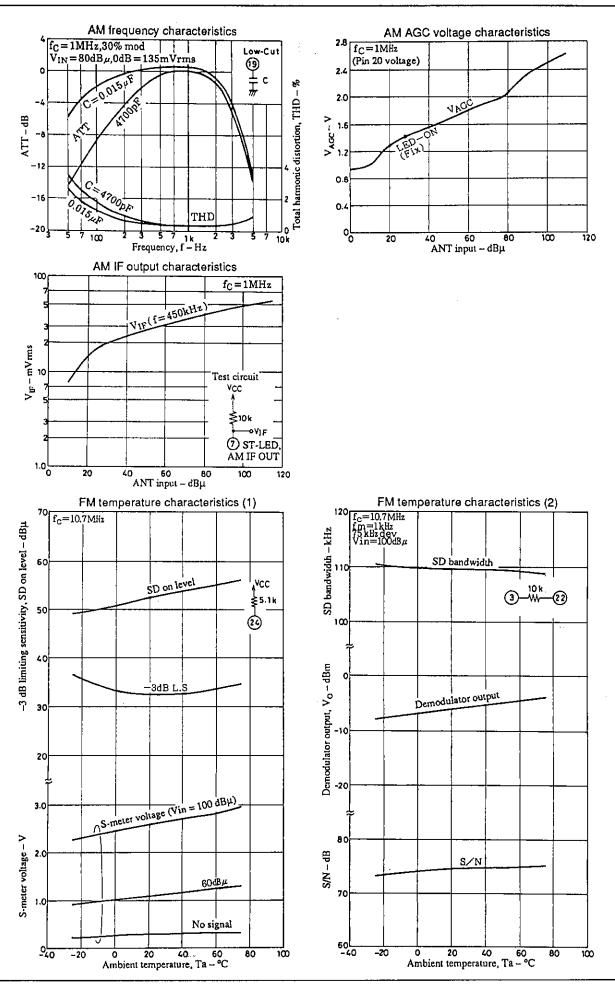


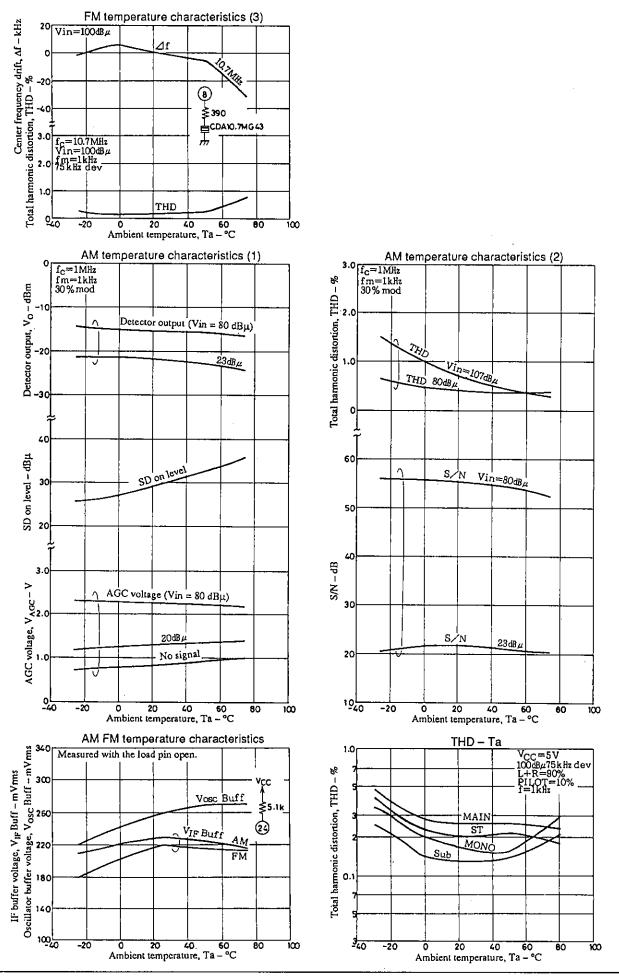
①-③ 15T $f_0 = 10.7 \text{ MHz}$ $Q_0 = 85 \pm 20\%$ 12 pF internal

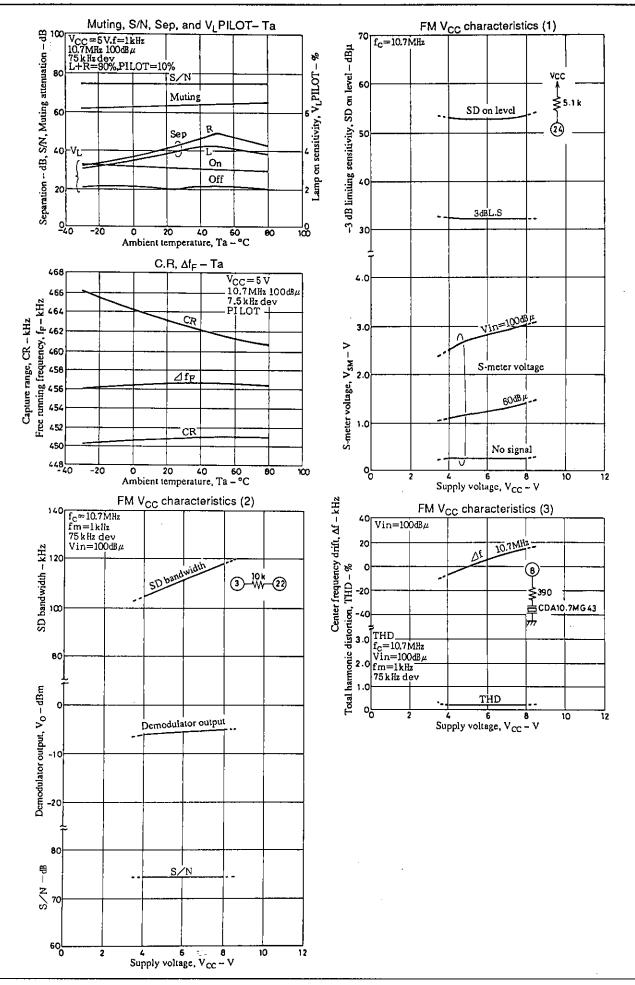
Unit (capacitance: F)

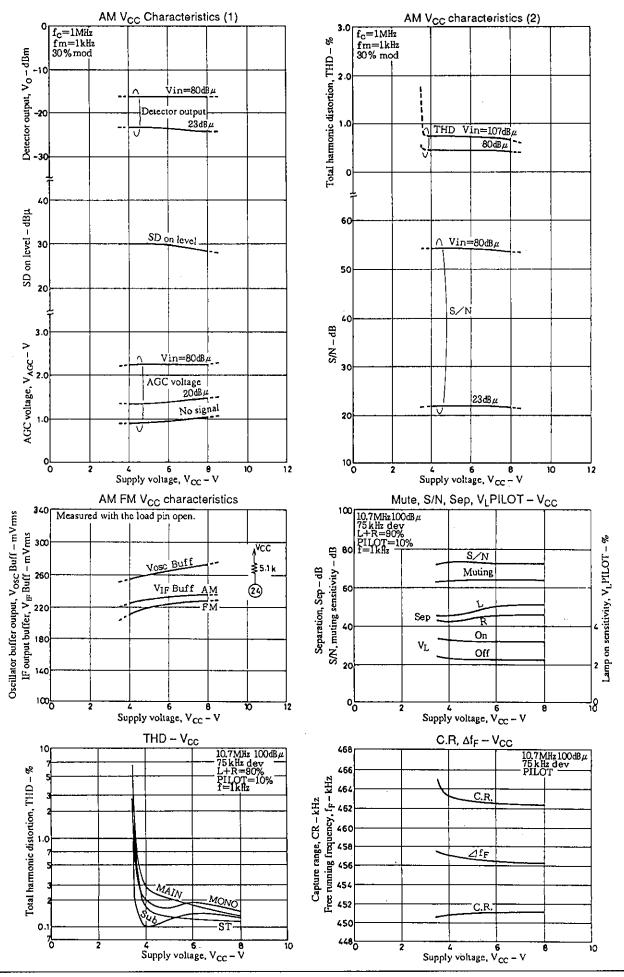
· Application circuit using an FM detector coil











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